

Maximum Ratings

Symbol	Conditions	Values	Units
$V_{CEV_{sus}}$	$I_C = 1\text{ A}$, $V_{BE} = -2\text{ V}$	1000	V
V_{CEV}	$V_{BE} = -2\text{ V}$	1000	V
V_{CBO}	$I_E = 0$	1000	V
V_{EBO}	$I_C = 0$	7	V
I_C	D. C.	300	A
$I_F = -I_C$	D. C.	300	A
I_B		16	A
P_{tot}	$T_{case} = 25\text{ °C}$	1980	W
T_{vj}		$-40 \dots +150$	°C
T_{stg}		$-40 \dots +125$	°C
V_{isol}	a. c. 50 Hz, r.m.s.	2500~	V

Thermal Characteristics

R_{thjc}	darlington	0,063	°C/W
R_{thjc}	diode	0,3	°C/W
R_{thch}	module	0,04	°C/W

Electrical Characteristics¹⁾

		min.	typ.	max.	
I_{CEV}	$V_{CE} = V_{CEV}$, $V_{BE} = -2\text{ V}$			4	mA
I_{EBO}	$I_C = 0$, $V_{BE} = -7\text{ V}$			800	mA
$V_{CEsat}^{2)}$	$I_C = 300\text{ A}$, $I_B = 6\text{ A}$			2,5	V
$V_{BEsat}^{2)}$	$I_C = 300\text{ A}$, $I_B = 6\text{ A}$			3,5	V
$h_{21E}^{2)}$	$I_C = 300\text{ A}$	$V_{CE} = 2,8\text{ V}$	75		
		$V_{CE} = 5\text{ V}$	100		

Switching Characteristics for Resistive Load¹⁾

t_{on}	$I_C = 300\text{ A}$ $I_{B1} = -I_{B2} = 6\text{ A}$ $V_{CC} = 600\text{ V}$		3	μs
t_s			15	μs
t_f			3	μs

Inverse Diode Characteristics¹⁾

$V_F = -V_{CE}$	$I_F = -I_C = 300\text{ A}$		1,8	V
$I_{FSM} = -I_{CP}$	$\sin 180^\circ$, 10 ms	3000		A
I_{RM}	$I_F = -I_C = 300\text{ A}$, $-di_F/dt = 100\text{ A}/\mu\text{s}$ $V_{BE} = -3\text{ V}$, $V_R = V_{CE} = 400\text{ V}$,		50	A
Q_{rr}	$T_{vj} = 125\text{ °C}$		25	μC

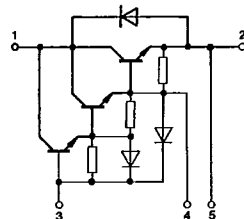
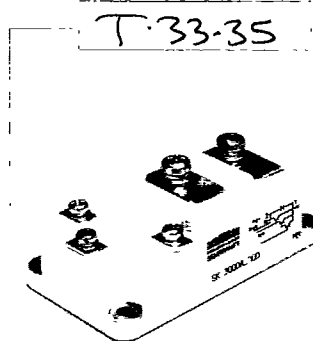
Mechanical Data

M_1	Case to heatsink	SI units	3		6	Nm
		US units	27		53	lb. in.
M_2	Busbars to	terminals 1, 2	SI units	2,5		5 Nm
			US units	22		44 lb. in.
		terminals 3 ... 5	SI units	1,1		2 Nm
			US units	10		18 lb. in.
w				475		g
Case				D 18		

SEMITRANS® 4 NPN

Power Darlington Modules 300 A, 1000 V

SK 300 DA 100 D



Features

- Isolated baseplate (ease of mounting of one or several modules on one heatsink)
- All electrical connections on top (ease of interconnecting of modules with busbars)
- Large clearances and creepage distances
- Parallel connected fast recovery inverse diode
- UL recognized, file no. E 63 532

Typical Applications

- Uninterruptible power supplies (UPS)
- DC drives
- AC motor controls

¹⁾ $T_{case} = 25\text{ °C}$ unless otherwise stated

²⁾ $t_p \leq 300\text{ μs}$, $D \leq 1,5\%$

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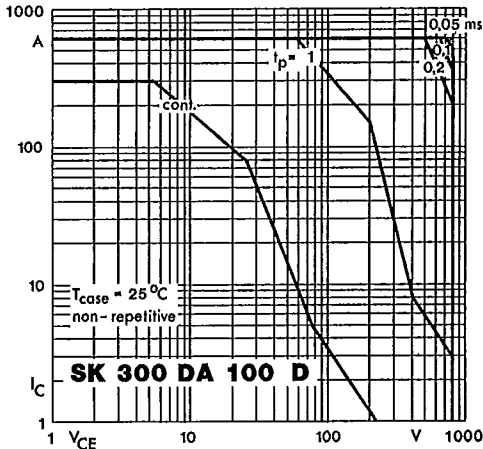


Fig. 1 Forward biased safe operating area (FBSOA)

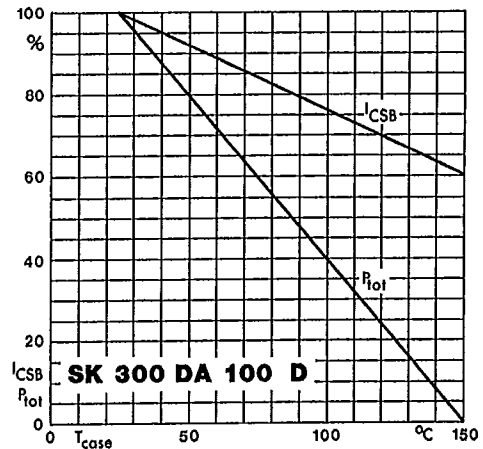


Fig. 2 Shifting the limits of the FBSOA with temperature

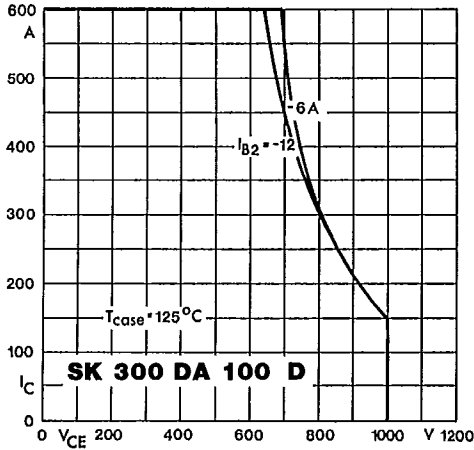


Fig. 3 Reverse biased safe operating area (RBSOA)

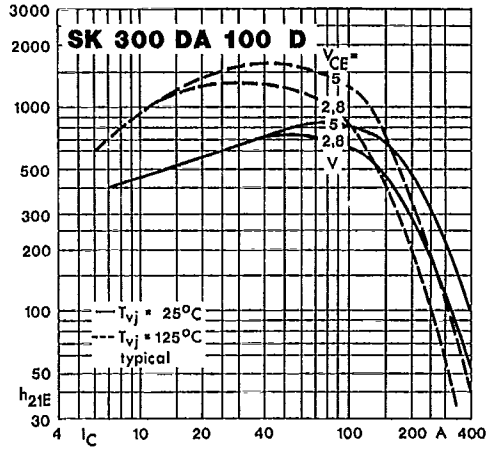


Fig. 4 Forward current transfer ratio vs. coll. current

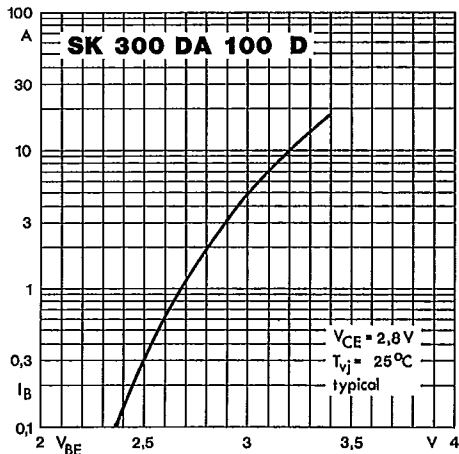


Fig. 5 Base current/voltage characteristic

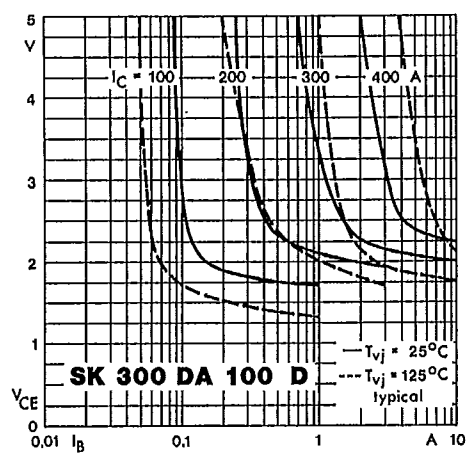


Fig. 6 Collector-emitter voltage vs. base current

